ENTRANCE EXAMINATIONS, JUNE 2012 QUESTION PAPER

Integrated M.Tech./Ph.D. and Ph.D. (Nano Science and Technology)

Marks: 75							
Time: 2.00 hrs	Hall Ticket no:						
II. Read th	your Booklet Code and Hall Ticket Number on the OMR Answer Sheet by you. Also write the Hall Ticket Number in the Space provided above. The following instructions carefully before answering the questions. Destion paper has TWO parts: PART 'A' and PART 'B'						
1. Part 'A':	Part 'A': It consists of 25 objective type questions of one mark each. There is a negative marking of 0.33 marks for every wrong answer. The marks obtained by a candidate in this part will be used for resolving tie cases.						
2. Part 'B':	It consists of 50 objective questions of one mark each. There is no negative marking in this part.						
me Own s	ns are to be answered. Answers for these questions are to be entered on heet, filling the appropriate circle against each question. For example, if to a question is (d), it should be marked as below:						
No additional itself and rou	l sheets will be provided. Rough work can be done in the question paper agh work sheets provided at the end of the booklet.						
4 Hand over be	of the greation monor hoof-less and state on the						

Hand over both the question paper booklet and the OMR answer sheet at the end of

- 5. Calculators are permitted. Log tables are not allowed. Mobile phones are not permitted inside the Examination Hall.
- 6. This book contains 19 pages including this cover sheet.

the examination.

PART 'A'

1.
$$\int \frac{dx}{a+bx}$$
 is

- A. $\frac{1}{b}\ln(a+bx)+c$
- B. $\ln(a+bx)+c$
- C. $b \ln(a + bx) + c$
- D. $\frac{1}{a}\ln(a+bx)+c$
- 2. The process used to introduce compressive residual stresses in near-surface regions for improving fatigue resistance
 - A. Electroslag remelting
 - B. Sand casting
 - C. Mechanical alloying
 - D. Laser shock peening
- 3. The fabrication step of mechanical grinding in nano science and technology is considered as an approach of
 - A. Bottom up
 - B. Top down
 - C. Middle up
 - D. Middle down
- 4. Equi channel angular pressing is
 - A. A Severe plastic deformation technique for producing ultrafine grained structures
 - B. A metal forming process for shaping flat sheets into cup shaped articles
 - C. A metal forming process to produce square shaped grooves
 - D. A method to produce coarse grain materials

- 5. Buckminster fullerene, a spherical molecule with the formula of C₆₀ comprises of
 - A. 12 pentagons and 20 hexagons
 - B. 10 pentagons and 20 hexagons
 - C. 12 pentagons and 18 hexagons
 - D. 14 pentagons and 18 hexagons
- 6. Mechanical alloying is a process in which grain refinement occurs
 - A. By mixing of metals in a liquid state
 - B. By alloying molten liquid by Aluminum
 - C. Due to co-precipitation in a chemical process
 - D. By repeated deformation, fracturing and cold welding of powder particles in a ball mill
- 7. Giant Magneto Resistance is
 - A. Resistance of a thin film structure to mechanical deformation
 - B. Resistance of a thin film structure to chemical degradation
 - C. A quantum mechanical phenomenon occurring in a multilayered thin film structure
 - D. A classical mechanical phenomenon occurring in a multilayered thin film structure
- 8. A sintering technique using pulsed DC current that directly passes through graphite dye and powder to be consolidated in case of conductive samples
 - A. Spark plasma sintering
 - B. Activated sintering
 - C. Liquid phase sintering
 - D. Microwave sintering
- 9. Polygonization is the phenomenon where
 - A. Dislocations disappear into grain boundaries,
 - B. Mobile dislocations present in the material are rearranged in cell walls
 - C. Dislocations are generated by the operation of Frank-Read sources
 - D. Dislocations form tangles

10. Ultimate tensile strength is given by

- A. Yield load/original area of cross section
- B. Yield load/instantaneous area of cross section
- C. Maximum load/instantaneous area of cross section
- D. Maximum load/original area of cross section

11. An example of line defects in crystals

- A. Dislocations
- B. Vacancies
- C. Stacking faults
- D. Interstitials

12. Fermi level of a metal defines

- A. The lowest occupied level of electron energies at absolute zero
- B. The highest occupied level of electron energies at room temperature
- C. The highest occupied level of electron energies at absolute zero
- D. The band gap in an intrinsic semi-conductor

13. In Hall-Petch equation, $\sigma_y = \sigma_i + kd^{-1/2}$, the relative hardening contribution of the grain boundaries is described by

- A. k, locking parameter
- B. d, grain diameter
- C. σ_y , yield stress
- D. σ_i, Frictional stress

14. Directional solidification can be used to produce

- A. Shape memory alloys
- B. Fuel clad tubes for nuclear reactors
- C. Materials for railway axles
- D. Turbine blades for gas turbine engines

- 15. The lowest density in a powder metallurgy product is its
 - A. Green density
 - B. Theoretical density
 - C. Sintered density
 - D. Smear density
- 16. Grain boundary sliding is promoted by
 - A. Elevated temperatures and low strain rate
 - B. Elevated temperatures and high strain rate
 - C. Sub zero temperatures and low strain rate
 - D. Ambient temperature and high strain rate
- 17. Which of the following is a semiconductor material?
 - A. Ge
 - B. CdS
 - C. GaP
 - D. All the above
- 18. Approximate boiling temperature of liquid nitrogen at STP conditions is
 - A. 273 K
 - B. 77 K
 - C. 4.2 K
 - D. 10 K
- 19. One of the following is an inert gas electron configuration
 - A. $1s^2 2s^2 2p^1$
 - B. $1s^2 2s^2 2p^6$
 - C. 1s²2s²2p⁶3s²3p² D. 1s²2s¹

- 20. Primitive cell of face centered cubic structure contains the following number of atoms
 - A. 4
 - B. 2
 - **C**. 1
 - D. 3
- 21. For materials with uniform grain size distribution, the ASTM grain size is derived from the equation, $n=2^{N-1}$ where n is the number of grains / inch². During microscopic examination, the ASTM index is determined from the observations made at a magnification of
 - A. 10 X
 - B. 100 X
 - C. 1000 X
 - D. 10000 X
- 22. A positive edge dislocation can be visualized as
 - A. Displacement of atoms from normal lattice positions into interstitial sites
 - B. As closed vacancy loops in the crystal
 - C. Insertion of extra half plane of atoms above the dislocation line
 - D. Insertion of extra half plane of atoms below the dislocation line
- 23. Expansion of materials occurs during heating due to
 - A. Only due to increase in lattice vibration amplitude
 - B. Increase in lattice vibration amplitude and increase in vacancy concentration
 - C. Increase in vacancy concentration
 - D. Annihilation of vacancies
- 24. The following material shows well defined fatigue limit
 - A. Mild steel
 - B. Aluminum
 - C. Alumina
 - D. Copper

- 25. Oxide dispersion strengthened alloys are generally produced by
 - A. Investment casting
 - B. Electroslag remelting
 - C. Rheocasting
 - D. Mechanical alloying

PART 'B'

- 26. The following elements contribute mainly to grain boundary strengthening in Ni base superalloys
 - A. Aluminum, Titanium, Niobium
 - B. Carbon, Boron, Zirconium
 - C. Chromium, Aluminum
 - D. Chromium, Molybdenum, Tungsten
- 27. The surface hardening process used for coating or cladding of a substrate for the purpose of reducing surface damage
 - A. Hardfacing
 - B. Carburizing
 - C. Flame hardening
 - D. Induction hardening
- 28. The product of complex number (4+2i) and (2+5i)
 - A. -4+20i
 - B. 6+10i
 - C. -2+24i
 - D. 2+24i
- 29. Cottrell atmosphere is associated with
 - A. Grain boundary shear
 - B. Formation of vacancy loops
 - C. Formation of slip band intrusion and extrusion
 - D. Yield point phenomenon
- 30. The S-N curve in low cycle fatigue region is described by
 - A. Goodman's relation
 - B. Coffin-Manson relationship
 - C. Basquin equation
 - D. Soderberg equation

31. During primary creep

- A. Creep resistance of the material increases by virtue of its own deformation
- B. A balance between strain hardening and recovery process takes place
- C. Internal void formation occurs
- D. Recrystallization or diffusional changes in the phases occur

32. Residual stresses are

- A. Stresses above offset yield strength
- B. Elastic stresses
- C. Close to ultimate tensile strength
- D. Close to true fracture stress
- 33. The usage of failed tensile test samples is mandatory to evaluate the following:
 - A. Yield strength and ultimate tensile strength
 - B. Ductility and percentage reduction area
 - C. Fracture strength and ultimate tensile strength
 - D. Elastic modulus and proportional limit
- 34. Peritectic reaction is given by:
 - A. Liquid+Solid1 \rightarrow Solid2
 - B. Liquid1+Liquid2→Liquid3
 - C. Solid1+Solid2→Liquid
 - D. Solid1+Solid2→Solid3
- 35. Millipede, a memory device based on a mechanical storage method uses an array of microcantilevers to create pattern of nanoindentation in a
 - A. Polymer medium
 - B. Molten salts
 - C. Molten metal
 - D. None of the above

- 36. Peak strengthening in age hardening Al-Cu alloys is derived from
 - A. Formation of coherent precipitate platelets of CuAl₂
 - B. The occurrence of an equilibrium phase CuAl₂
 - C. Ordering of copper atoms on {100} planes of matrix
 - D. Local clustering of copper atoms
- 37. The nuclear fuel in pressurized heavy water reactors in India is
 - A. Oxides of Thorium and Plutonium
 - B. Plutonium oxide
 - C. Natural Uranium oxide
 - D. Enriched U²³⁵
- 38. In fusion reactor based on the concept of magnetic confinement of plasma isotopes of the following are used for energy generation
 - A. Plutonium
 - B. Thorium
 - C. Uranium
 - D. Hydrogen
- 39. The following alloys are used as electrodes for resistance welding
 - A. Cu-Cr
 - B. Al-Si
 - C. Cu-Zn
 - D. Sb-Sn
- 40. The following is correct in case of nanocrystalline materials with respect to those of conventional grain size
 - A. The melting point is high
 - B. The grain boundary specific area is more
 - C. The density is high
 - D. The weight is more

- 41. Diffusion flux has the units of
 - A. No. of atoms/(area . time)
 - B. No. of atoms/(volume . time)
 - C. No. of atoms/(length . time)
 - D. No. of atoms/(mass.time)
- 42. Tabling process is unit operation for extraction of
 - A. Lead
 - B. Silicon
 - C. Gold
 - D. Copper
- 43. For a closed system of fixed internal energy and volume, at equilibrium
 - A. Gibbs free energy is minimum
 - B. Enthalpy is maximum
 - C. Helmoltz's free energy is minimum
 - D. Entropy is maximum
- 44. In the limit $x \to \infty$, $y = \sqrt{x} (\sqrt{x+4} \sqrt{x})$ is
 - A. 2
 - B. 0
 - C. 1/2
 - D. does not exist
- 45. The included angle between the opposite faces of diamond pyramid indenter used in Vicker's hardness test is
 - A. 180°
 - B. 136°
 - C. 90°
 - D. 0°
- 46. Cold working of a metallic material is carried out
 - A. At its recrystallization temperature
 - B. Below brittle to ductile transition temperature
 - C. Above its recrystallization temperature
 - D. Below its recrystallization temperature

47. Tetragonal phase ZrO ₂ can be stabilized down to room temperature by adding a amount of					
ΔSn					

- A. Sn
- B. Be
- C. Y₂O₃
- D. La
- 48. Magnetically hard ferrites used for loud speakers, telephone ringers and receivers have the general formula MO.6Fe₂O₃ where M is usually
 - A. Ba or Sr ion
 - B. Fe, Mn or Ni ion
 - C. Fe or Si ion
 - D. None of the above
- 49. The metallic materials that are widely being used for hip joints in human body are
 - A. Niobium alloys
 - B. Copper alloys
 - C. Mild steel
 - D. Titanium alloys
- 50. The condensed phase rule is represented by
 - A. F=C-P+1
 - B. F=C-P-1
 - C. F=C-P+2
 - D. F=C-P-2
- 51. The following has the highest co-efficient of thermal expansion
 - A. Plastics
 - B. Ceramics
 - C. Tungsten
 - D. Tin

- 52. Curie temperature is a useful concept for
 - A. Ferro-magnetic material
 - B. Superplastic material
 - C. Ferro-elastic material
 - D. Dielectric material
- 53. Zinc has even number of electrons in the outer shell and a full valence band, therefore
 - A. Zinc is an insulator
 - B. Zinc is a semi-conductor
 - C. Zinc is a conductor
 - D. None of the above
- 54. The neutron capture cross-section is customarily measure in barns. 1 barn equals to
 - A. 10^{-28} m^2
 - B. 10⁻²⁷ m²
 - C. 10^{-26} m^2
 - D. 10^{-25} m^2
- 55. A small portion of In is incorporated in a Ge crystal. Ge crystal is now
 - A. A conductor
 - B. An insulator
 - C. A n-type semiconductor
 - D. A p-type semiconductor
- 56. For continuous machining applications the following tool materials are primarily used
 - A. High speed steel
 - B. Cast cobalt alloy
 - C. Cementite carbides
 - D. None of the above
- 57. The improvement in high cycle fatigue resistance of steel is obtained by having
 - A. Surface decarburization
 - B. Fine grain size
 - C. Tensile residual stresses on surface
 - D. Presence of globular inclusions of oxides

- 58. Refinement of grain size in Magnesium alloys is carried out by the addition of
 - A. Manganese
 - B. Zinc
 - C. Zirconium
 - D. Cerium
- 59. Top-down approach is generally employed
 - A. To activate the particles without altering the particle size of powders
 - B. For increasing the particle size of powders
 - C. For reducing the particle size of powders
 - D. None of the above
- 60. Differential Scanning Calorimetry is used for the determination of
 - A. Phase transformations
 - B. Surface topography
 - C. Co-efficient of thermal expansion
 - D. Grain boundary chemical analysis
- 61. A very large Reynold's number is an indication of
 - A. Laminar flow
 - B. High turbulent flow
 - C. Smooth and streamline flow
 - D. None of the above
- 62. The point defects strengthen metals and decrease their ductility by
 - A. Impeding the motion of dislocation
 - B. Promoting ionic bonding
 - C. Promoting covalent bonding
 - D. Increasing the density of metal
- 63. A free radical can be best detected by
 - A. Electron Spin Resonance
 - B. Nuclear Magnetic Resonance
 - C. Infrared Spectroscopy
 - D. Nuclear Quadrapole Resonance

- 64. Which of the following statements is true?
 - A. Reaction temperatures in plasma enhanced chemical vapor deposition are greater than in thermal chemical vapor deposition
 - B. Reaction temperatures in plasma enhanced chemical vapor deposition are less than in thermal chemical vapor deposition
 - C. Reaction temperatures in plasma enhanced chemical vapor deposition are equal to those in thermal chemical vapor deposition
 - D. None of the above
- 65. The following technique has the ability to carry out precise and controlled manipulation of atoms, molecules and nanostructures
 - A. X-ray photoelectron spectroscopy
 - B. High resolution transmission electron microscope
 - C. Scanning Tunneling Microscopy
 - D. Optical microscopy
- 66. The relationship between Young's modulus (E), modulus of rigidity (η) and Poisson's ration (υ) is
 - A. $E=\eta(1+v)$
 - B. $v=2E/(1+\eta)$
 - C. $\eta = 2E(1+v)$
 - D. $E=2\eta(1+v)$
- 67. The energy of neutrons that cause fission in thermal nuclear reactors is
 - A. 14 MeV
 - B. 25 keV
 - C. 0.25 eV
 - D. >0.1 MeV
- 68. Presence of super-lattice line/peak in an x-ray diffractogram of a solid indicates the presence of
 - A. Nucleation of precipicates
 - B. Long range ordering
 - C. Immiscibility of alloying elements
 - D. Overaged precipitates

- 69. The total area under stress-strain curve represents
 - A. Fracture strength
 - B. Malleability
 - C. Toughness
 - D. Resilience
- 70. The term diamond-like-carbon is most commonly used to refer to
 - A. Graphene layers
 - B. Amorphous carbon thin films
 - C. Crystalline diamond composites
 - D. All of the above
- 71. Sensitization in stainless steels is associated with
 - A. Depletion of Carbon to less than 0.2% at grain boundaries
 - B. Depletion of Chromium to less than 12% at grain boundaries
 - C. Depletion of Nickel to less than 8% at grain boundaries
 - D. Depletion of Titanium to less than 0.5% at grain boundaries
- 72. In the superconducting state, the electrical resistivity of a material is
 - A. One tenth its normal value
 - B. Ten times the normal value
 - C. Zero
 - D. Unaltered
- 73. Perspex is a
 - A. Metal
 - B. Ceramic
 - C. Gas
 - D. Polymeric material
- 74. A material with zero co-efficient of thermal expansion is
 - A. Invar
 - B. Nd-B compound
 - C. Tungsten
 - D. Celluloid

75. Energy gap of Germanium at room temperature is

A. 5.0 eV

B. 1.5 eV

C. 1.1 eV

D. 0.7 eV